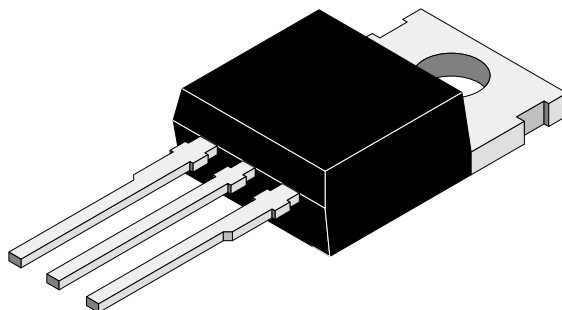




10A Schottky Barrier Rectifier

Features

- Schottky barrier chip
- Guard ring die construction for transient protection
- Low power loss, high efficiency
- High current capability and low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection application
- Plastic material – UL Recognition flammability classification 94V-0



95 9630

Absolute Maximum Ratings

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Value	Unit
Repetitive peak reverse voltage =Working peak reverse voltage =DC Blocking voltage		SBL1030CT	V_{RRM} $=V_{RWM}$ $=V_R$	30	V
		SBL1035CT		35	V
		SBL1040CT		40	V
		SBL1045CT		45	V
		SBL1050CT		50	V
		SBL1060CT		60	V
Peak forward surge current			I_{FSM}	175	A
Average forward current	$T_C = 95^\circ\text{C}$		I_{FAV}	10	A
Junction and storage temperature range			$T_j = T_{stg}$	-65...+150	$^\circ\text{C}$

Electrical Characteristics

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F = 5\text{A}$, $T_C = 25^\circ\text{C}$	SBL1030CT–SBL1045CT	V_F			0.55	V
		SBL1050CT–SBL1060CT	V_F			0.70	V
Reverse current	$T_C = 25^\circ\text{C}$		I_R			0.5	mA
	$T_C = 125^\circ\text{C}$		I_R			50	mA
Diode capacitance	$V_R = 4\text{V}$, $f = 1\text{MHz}$		C_D		450		pF
Thermal resistance junction to case	$T_L = \text{const.}$		R_{thJC}		5.5		K/W

Characteristics ($T_j = 25^\circ\text{C}$ unless otherwise specified)

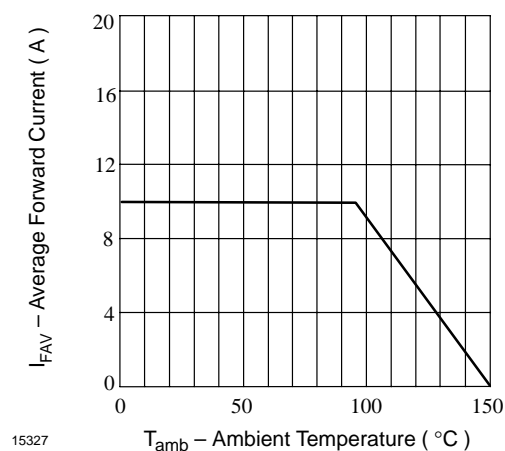


Figure 1. Max. Average Forward Current vs. Ambient Temperature

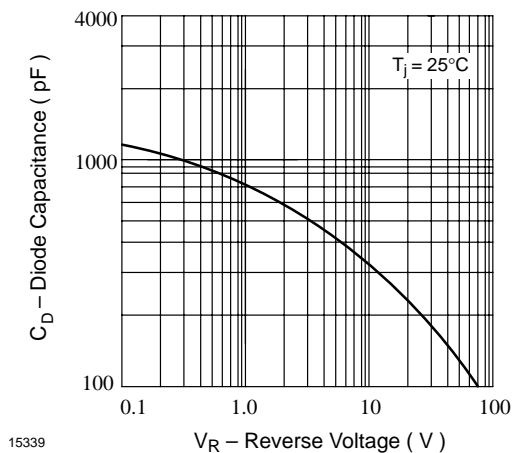


Figure 4. Typ. Diode Capacitance vs. Reverse Voltage

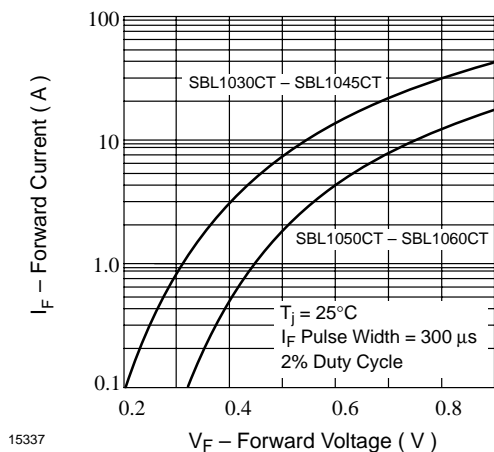


Figure 2. Typ. Forward Current vs. Forward Voltage

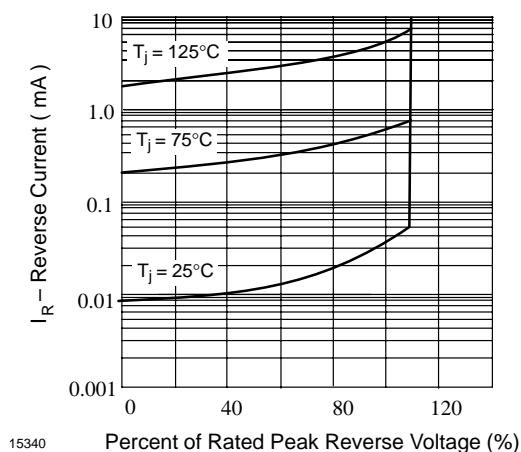


Figure 5. Typ. Reverse Current vs. Percent of Rated Peak Reverse Voltage

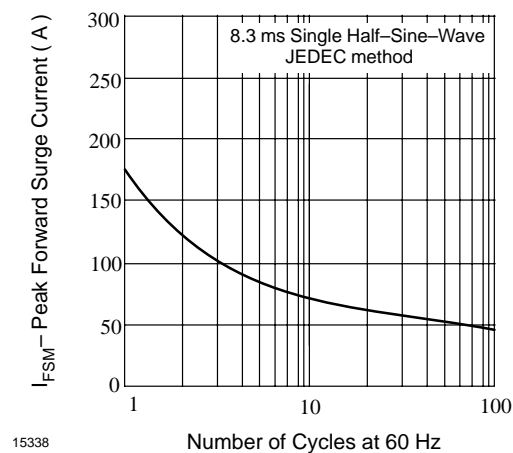


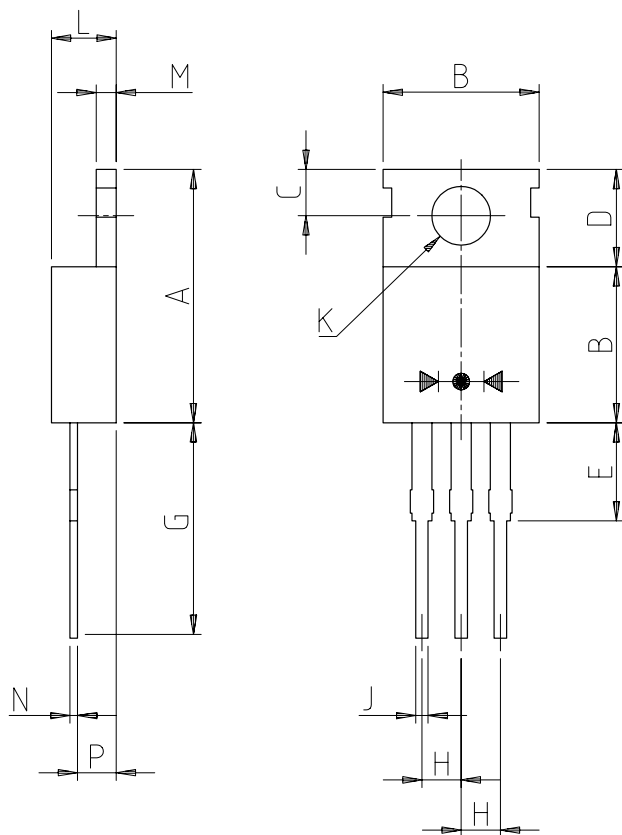
Figure 3. Max. Peak Forward Surge Current vs. Number of Cycles



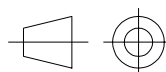
SBL1030CT–SBL1060CT

Vishay Lite-On Power Semiconductor

Dimensions in mm



TO-220AB		
Dim	Min	Max
A	14.22	15.88
B	9.65	10.67
C	2.54	3.43
D	5.84	6.86
E	-	6.25
G	12.70	14.73
H	2.29	2.79
J	0.51	1.14
K	∅3.53	∅4.09
L	3.56	4.83
M	1.14	1.40
N	0.30	0.64
P	2.03	2.92
All Dimensions in mm		



technical drawings
according to DIN
specifications

14468

Case: molded plastic
Polarity: as marked on body
Approx. weight: 2.24 grams
Mounting position: any
Marking: type number



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0) 7131 67 2831, Fax number: 49 (0) 7131 67 2423